

# **BIPRO**

TP7G60M TP7G60M(H) **120-cell** 

440 - 460W

Bifacial Module With Transparent Backsheet 10BB Half-cut Mono Perc



near Performance Warranty





# 10BB Half-cut Cell Technology

New circuit design, lower internal current, lower Rs loss Ga dopped wafer, attenuation < 2% (1st year) / 0.55% (Linear)



# Significantly Lower the Risk of Hot Spot

Special circuit design with much lower hot spot temperature



## Lower LC0E

2% more power generation, lower LCOE



# **Excellent Anti-PID Performance**

2 times of industry standard Anti-PID test



## IP68 Junction Box

High waterproof level



#### **ELECTRICAL CHARACTERISTICS**

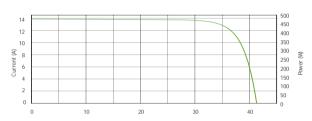
			 				1 1 1 1		
440	328	445	332	450	336	455	339	460	343
34.35	32.1	34.53	32.2	34.70	32.4	34.87	32.6	35.04	32.7
12.81	10.23	12.89	10.30	12.97	10.36	13.05	10.42	13.13	10.49
40.99	38.6	41.16	38.7	41.33	38.9	41.50	39.1	41.67	39.2
13.69	11.04	13.78	11.11	13.86	11.17	13.94	11.24	14.02	11.30
20.	30	20.	60	20.	80	21	.00	21	.30

°C.

#### **MECHANICAL CHARACTERISTICS**

Monocrystalline Silicon (10Busbar)	
120pcs in series (6*20)	
1908*1134*35mm (75.12*44.65*1.38inches)	
24.3kg (53.6lbs.)	
3.2mm AR Coating Tempered Glass	
Anodized Aluminium Alloy	
IP68, 3 Bypass Diodes	
4mm² (IEC), 12AWG(UL) 300mm in Length or Customized Length	
T01/LJQ-3-CSY/MC4/MC4-EVO2	

# I-V CURVE



# **APPLICATION CONDITIONS**

1000V/1500V/DC		
-40°C~+85°C		
30A		
Class II		

# **TECHNICAL DRAWINGS**

# **TEMPERATURE CHARACTERISTICS**

-0.35%/°C
-0.26%/°C
+0.048%/°C
43±2°C

# **PACKING CONFIGURATION**

31	31(USA)
744	744

